

## isc Triacs

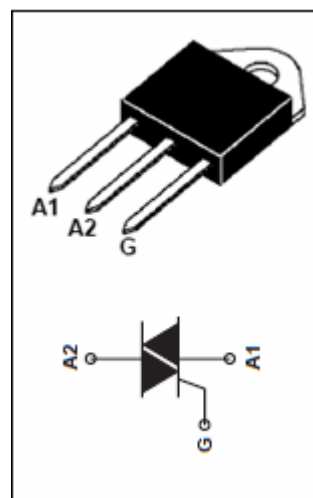
## BTA26-600B

## FEATURES

- With TO-3P insulated package
- Suitable for general purpose where high surge current capability is required. Application such as phase control and static switching on inductive or resistive load.

## ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	MIN	UNIT
$V_{DRM}$	Repetitive peak off-state voltage	600	V
$V_{RRM}$	Repetitive peak reverse voltage	600	V
$I_{T(RMS)}$	RMS on-state current (full sine wave) $T_j=90^\circ\text{C}$	25	A
$I_{TSM}$	Non-repetitive peak on-state current $t_p=8.3\text{ms}$	260	A
$T_j$	Operating junction temperature	125	°C
$T_{stg}$	Storage temperature	-45~150	°C
$P_{G(AV)}$	Average gate power dissipation( $T_j=125^\circ\text{C}$ )	1	W
$R_{th(j-c)}$	Thermal resistance, junction to case	1.5	°C/W
$R_{th(j-a)}$	Thermal resistance, junction to ambient	50	°C/W

ELECTRICAL CHARACTERISTICS ( $T_C=25^\circ\text{C}$  unless otherwise specified)

SYMBOL	PARAMETER	CONDITIONS	MAX	UNIT	
$I_{RRM}$	Repetitive peak reverse current	$V_R=V_{RRM}$ , $V_R=V_{RRM}$ , $T_j=125^\circ\text{C}$	0.01 6.0	mA	
$I_{DRM}$	Repetitive peak off-state current	$V_D=V_{DRM}$ , $V_D=V_{DRM}$ , $T_j=125^\circ\text{C}$	0.01 6.0	mA	
$I_{GT}$	Gate trigger current	$V_D=12\text{V}$ ; $R_L=33\ \Omega$	I	50	mA
			II	50	
			III	50	
			IV	100	
$I_H$	Holding current	$I_{GT}=0.5\text{A}$ , Gate Open	80	mA	
$V_{GT}$	Gate trigger voltage all quadrant	$V_D=12\text{V}$ ; $R_L=33\ \Omega$	1.5	V	
$V_{TM}$	On-state voltage	$I_T=35\text{A}$ ; $t_p=380\ \mu\text{s}$	1.7	V	